



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

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Features

- 0.3" (7.62mm) Matrix Height
- Single Digit Display
- Black/Grey Face , White Segment
- IC compatible, Easy assembly
- Dynamic drive connect
- RoHS Compliant, Pb Free

Applications

- Consumer Electronics
- Industrial Equipment

Description

The INND-SS30 series is a 0.3" single digit display. It is a SMD type LED display which can be used in various applications.

Internal Circuit Diagram

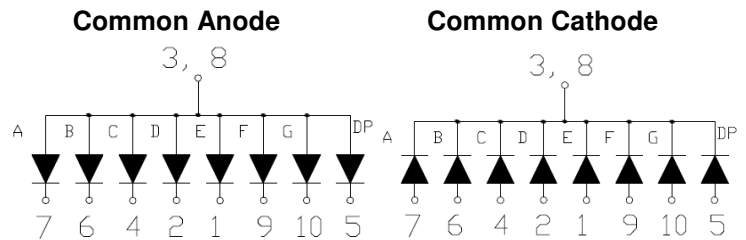


Figure 1. INND-SS30 series Internal Circuit Diagram

Package Dimensions

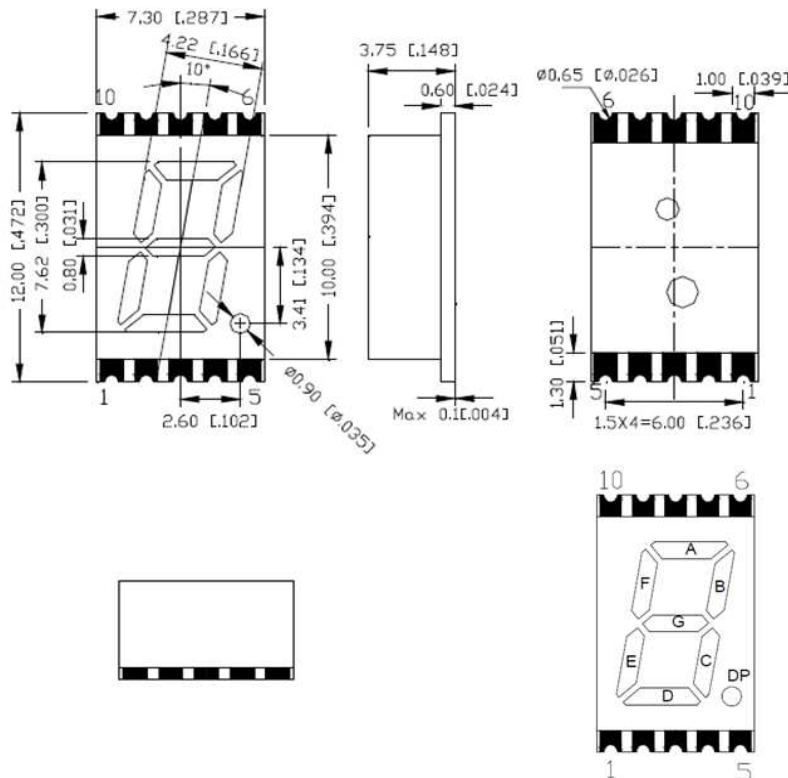


Figure 2. INND-SS30 series Package Dimensions

Absolute Maximum Rating at 25°C (Note 1)

| Product (Per Segment) | Emission Color | Technology | Pd (mW) | IF (mA) | IFP* (mA) | VR (V) | Derate From 25°C (mA/°C) | T _{OP} (°C) | T _{ST} (°C) |
|--------------------------|-------------------|------------|---------|---------|--------------|--------|-----------------------------|----------------------|----------------------|
| INND-SS30YGXX | Yellow Green | AlGaInP | 70 | 25 | 90 | 5 | 0.33 | -40°C~+105°C | -40°C~+105°C |
| INND-SS30YXX | Yellow | AlGaInP | 70 | 25 | 90 | 5 | 0.33 | -40°C~+105°C | -40°C~+105°C |
| INND-SS30AXX | Amber | AlGaInP | 70 | 25 | 90 | 5 | 0.33 | -40°C~+105°C | -40°C~+105°C |
| INND-SS30RXX | Red | AlGaInP | 70 | 25 | 90 | 5 | 0.33 | -40°C~+105°C | -40°C~+105°C |
| INND-SS30DRXX | Deep Red | AlGaInP | 70 | 25 | 90 | 5 | 0.33 | -40°C~+105°C | -40°C~+105°C |
| INND-SS30GXX | Green | InGaIn | 114 | 30 | 100 | 5 | 0.4 | -40°C~+105°C | -40°C~+105°C |
| INND-SS30BXX | Blue | InGaIn | 114 | 30 | 100 | 5 | 0.4 | -40°C~+105°C | -40°C~+105°C |
| INND-SS30WXX | White | InGaIn | 114 | 30 | 100 | 5 | 0.4 | -40°C~+105°C | -40°C~+105°C |

Notes

1. Condition for IFP is pulse of 1/10 duty and 0.1msec width

Electrical Characteristics $T_A = 25^\circ\text{C}$ (Note 1)

| Product (Per Segment) | Emission Color | $V_F(\text{V})@20\text{mA}$ | | | $\lambda(\text{nm})@20\text{mA}$ | | $I_V(\text{mcd})@10\text{mA}$ | | | $I_R(\mu\text{A})@V_R=5\text{V}$ | $I_{V-M}@I_F=10\text{mA}$ |
|--------------------------|-------------------|-----------------------------|------|-----|----------------------------------|-------------|-------------------------------|------|-----|----------------------------------|---------------------------|
| | | min | typ. | max | λ_D | λ_P | min | typ. | max | max | max |
| INND-SS30YGXX | Yellow Green | - | 2.0 | 2.8 | 570 | 572 | - | 2 | - | 100 | 2:1 |
| INND-SS30YXX | Yellow | - | 2.0 | 2.8 | 590 | 592 | - | 8 | - | 100 | 2:1 |
| INND-SS30AXX | Amber | - | 2.0 | 2.8 | 605 | 612 | - | 9 | - | 100 | 2:1 |
| INND-SS30RXX | Red | - | 2.0 | 2.8 | 630 | 644 | - | 5 | - | 100 | 2:1 |
| INND-SS30DRXX | Deep Red | - | 2.0 | 2.8 | 645 | 660 | - | 2 | - | 100 | 2:1 |
| INND-SS30GXX | Green | - | 3.2 | 3.8 | 525 | - | - | 37 | - | 100 | 2:1 |
| INND-SS30BXX | Blue | - | 3.2 | 3.8 | 465 | - | - | 7 | - | 50 | 2:1 |
| INND-SS30WXX | White | - | 3.2 | 3.8 | X: 0.27 Y: 0.25 | - | 10.7 | 19.3 | - | 50 | 2:1 |

Notes

1. Performance guaranteed only under conditions listed in above tables.

ESD Precaution

ATTENTION: Electrostatic Discharge (ESD) protection



The symbol above denotes that ESD precaution is needed. ESD protection for GaP and AlGaAs based chips is necessary even though they are relatively safe in the presence of low static-electric discharge. Parts built with AlInGaP, GaN, or/and InGaN based chips are STATIC SENSITIVE devices. ESD precaution must be taken during design and assembly. If manual work or processing is needed, please ensure the device is adequately protected from ESD during the process.

Please be advised that normal static precautions should be taken in the handling and assembly of this device to prevent damage or degradation which may be induced by electrostatic discharge (ESD).

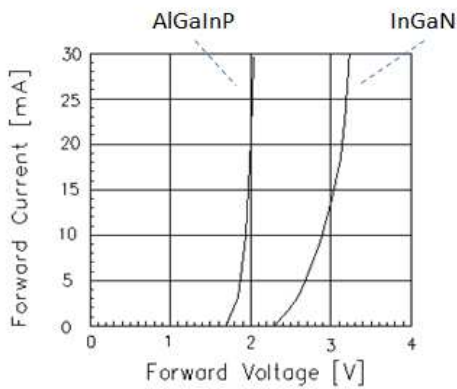
Characteristic Curves for YG, Y, A, R, DR, G


Fig 1. Forward Current vs. Forward Voltage

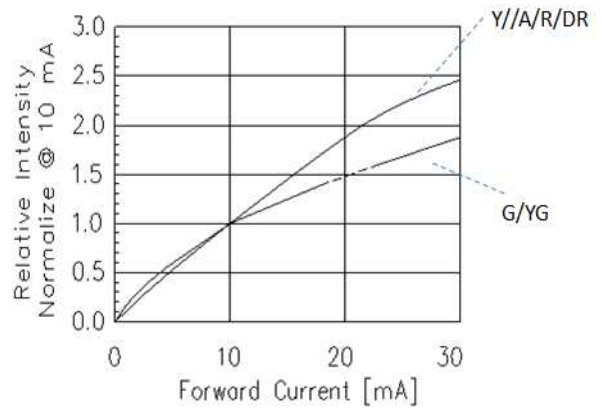


Fig 2. Relative Intensity vs. Forward Current

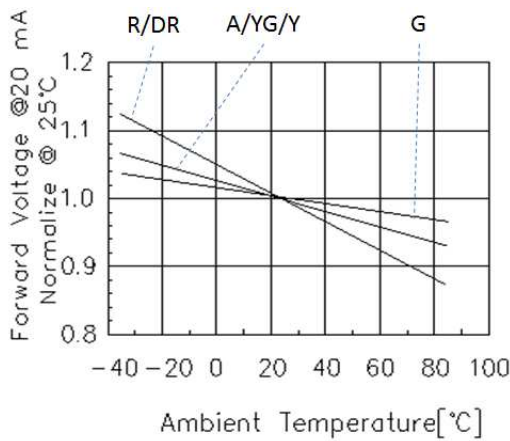


Fig 3. Forward Voltage vs. Temperature

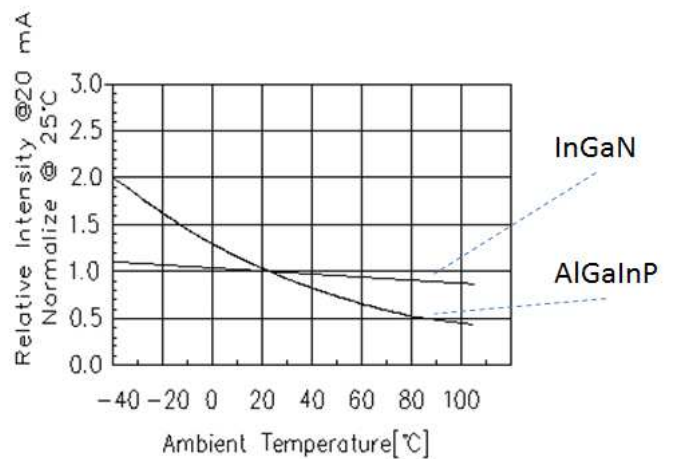


Fig 4. Relative Intensity vs. Temperature

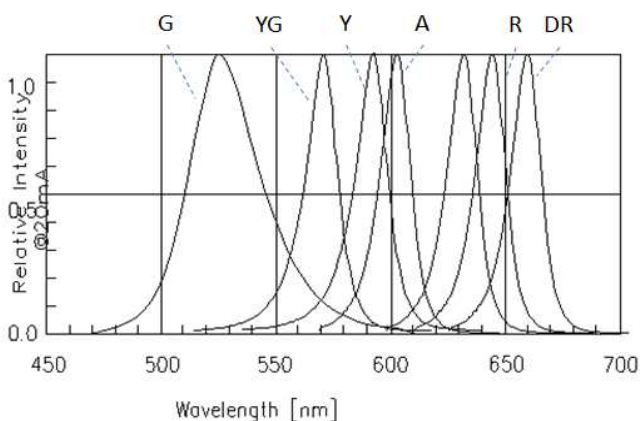


Fig 5. Relative Intensity vs. Wavelength

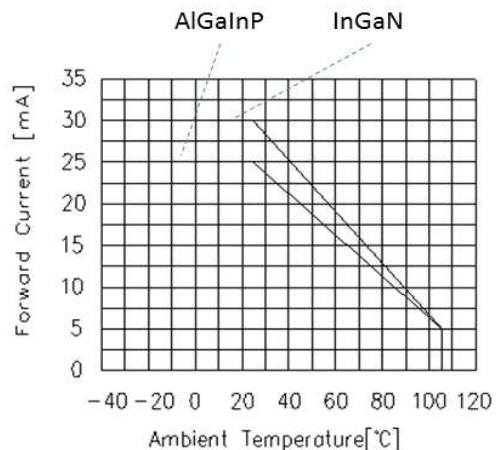


Fig 6. Forward current vs. Temperature

Characteristic Curves for B

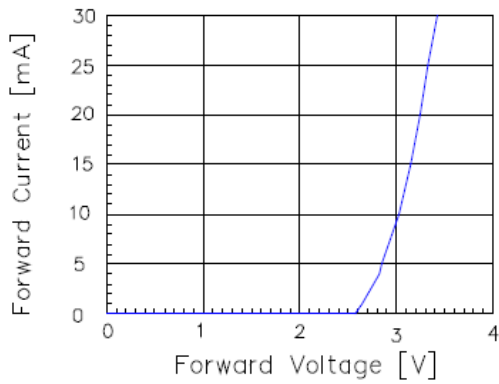


Fig 1. Forward Current vs. Forward Voltage

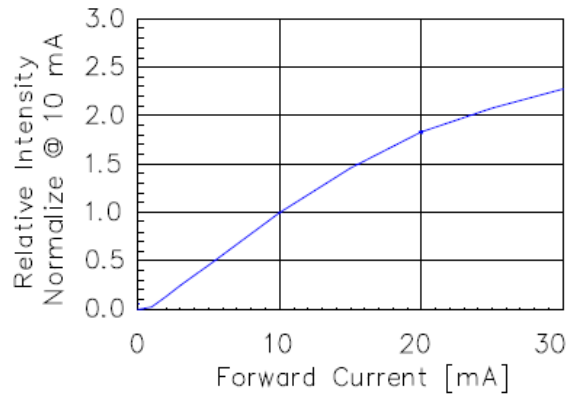


Fig 2. Relative Intensity vs. Forward Current

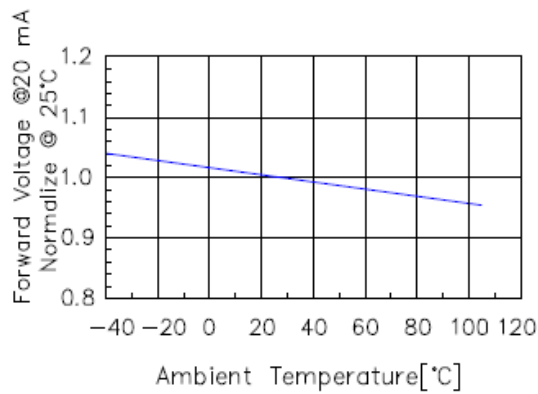


Fig 3. Forward Voltage vs. Temperature

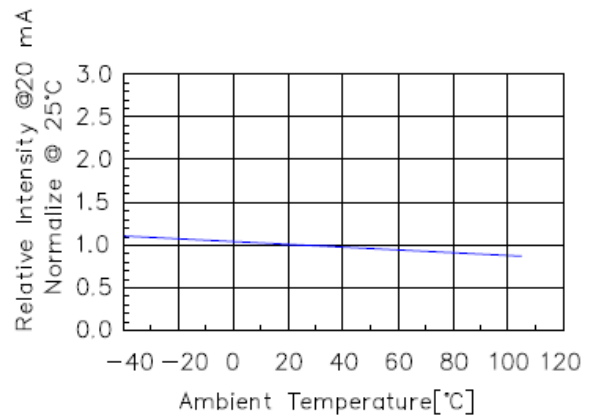


Fig 4. Relative Intensity vs. Temperature

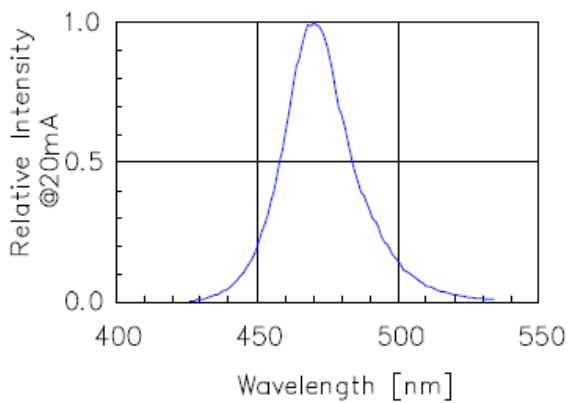


Fig 5. Relative Intensity vs. Wavelength

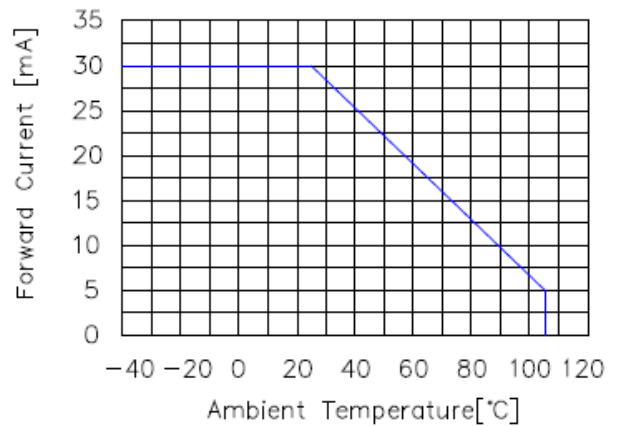


Fig 6. Forward current vs. Temperature

Characteristic Curves for W

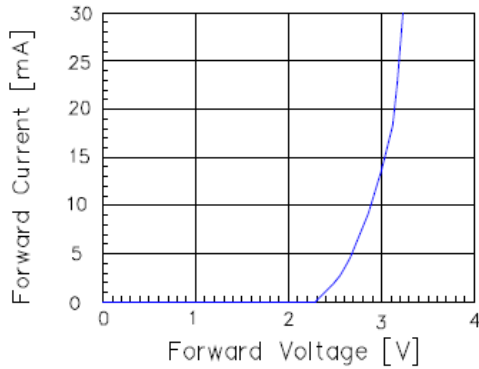


Fig 1. Forward Current vs. Forward Voltage

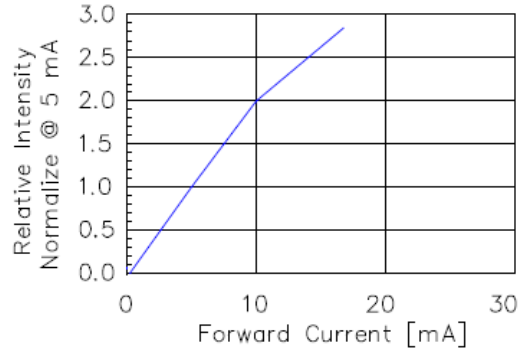


Fig 2. Relative Intensity vs. Forward Current

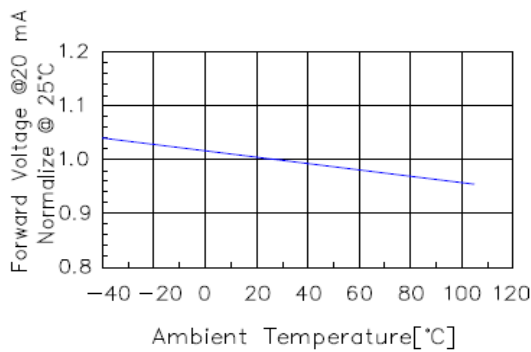


Fig 3. Forward Voltage vs. Temperature

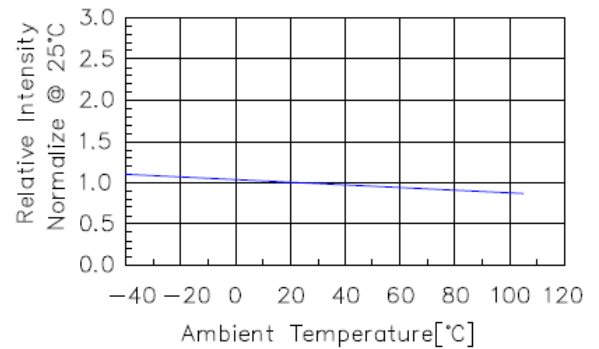


Fig 4. Relative Intensity vs. Temperature

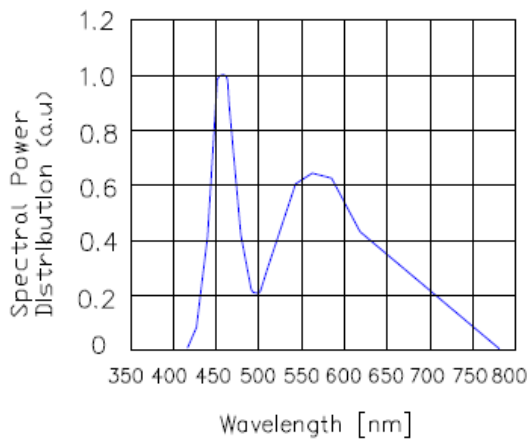


Fig 5. Spectral Power Distribution vs. Wavelength

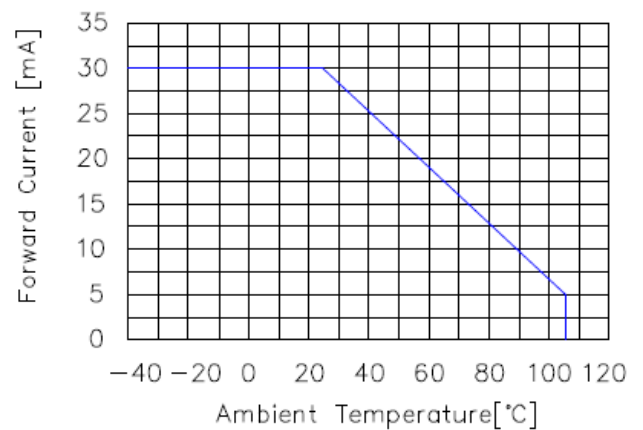
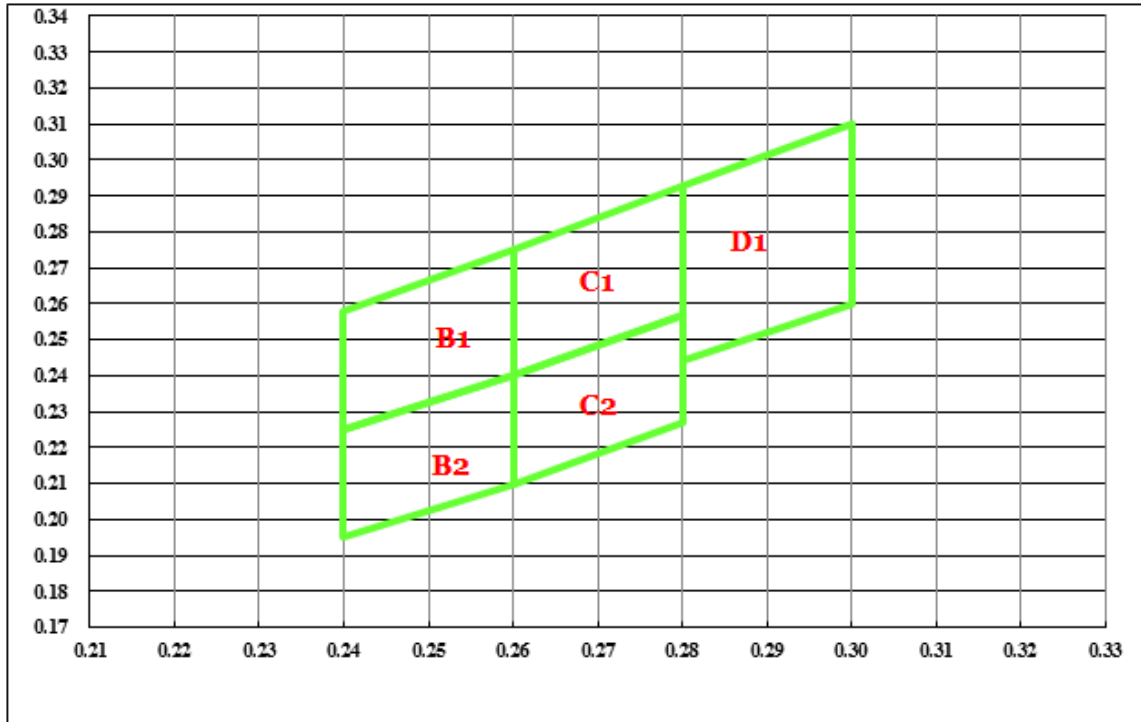


Fig 6. Forward current vs. Temperature

Chromaticity Bin (for White only)


| B1 | | | | |
|----|-------|-------|-------|-------|
| X | 0.240 | 0.240 | 0.260 | 0.260 |
| Y | 0.225 | 0.258 | 0.275 | 0.240 |

| B2 | | | | |
|----|-------|-------|-------|-------|
| X | 0.240 | 0.240 | 0.260 | 0.260 |
| Y | 0.195 | 0.225 | 0.240 | 0.210 |

| C1 | | | | |
|----|-------|-------|-------|-------|
| X | 0.260 | 0.260 | 0.280 | 0.280 |
| Y | 0.240 | 0.275 | 0.293 | 0.257 |

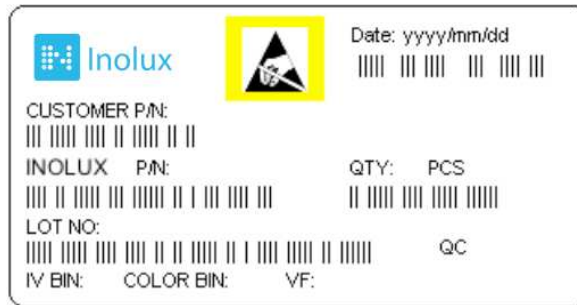
| C2 | | | | |
|----|-------|-------|-------|-------|
| X | 0.260 | 0.260 | 0.280 | 0.280 |
| Y | 0.210 | 0.240 | 0.257 | 0.227 |

| D1 | | | | |
|----|-------|-------|-------|-------|
| X | 0.280 | 0.280 | 0.300 | 0.300 |
| Y | 0.244 | 0.293 | 0.310 | 0.260 |

Ordering Information

| Product | Emission Color | Technology | I*V(mcd) @10mA | VF(V) @20mA | Polarity | Face Color | Orderable Part Number |
|---------------|----------------|------------|-------------------|----------------|----------------|------------|-----------------------|
| INND-SS30YGXX | Yellow Green | AlGaInP | 2 | 2.0 | Common Anode | Black | INND-SS30YGAB |
| | | | | | Common Cathode | Black | INND-SS30YGCB |
| | | | | | Common Anode | Grey | INND-SS30YGAG |
| | | | | | Common Cathode | Grey | INND-SS30YGCG |
| INND-SS30YXX | Yellow | AlGaInP | 8 | 2.0 | Common Anode | Black | INND-SS30YAB |
| | | | | | Common Cathode | Black | INND-SS30YCB |
| | | | | | Common Anode | Grey | INND-SS30YAG |
| | | | | | Common Cathode | Grey | INND-SS30YCG |
| INND-SS30AXX | Amber | AlGaInP | 9 | 2.0 | Common Anode | Black | INND-SS30AAB |
| | | | | | Common Cathode | Black | INND-SS30ACB |
| | | | | | Common Anode | Grey | INND-SS30AAG |
| | | | | | Common Cathode | Grey | INND-SS30ACG |
| INND-SS30RXX | Red | AlGaInP | 5 | 2.0 | Common Anode | Black | INND-SS30RAB |
| | | | | | Common Cathode | Black | INND-SS30RCB |
| | | | | | Common Anode | Grey | INND-SS30RAG |
| | | | | | Common Cathode | Grey | INND-SS30RCG |

| Product | Emission Color | Technology | I*V(mcd) @10mA | VF(V) @20mA | Polarity | Face Color | Orderable Part Number |
|---------------|----------------|------------|-------------------|----------------|----------------|------------|-----------------------|
| INND-SS30DRXX | Deep Red | AlGaInP | 2 | 2.0 | Common Anode | Black | INND-SS30DRAB |
| | | | | | Common Cathode | Black | INND-SS30DRCB |
| | | | | | Common Anode | Grey | INND-SS30DRAG |
| | | | | | Common Cathode | Grey | INND-SS30DRCG |
| INND-SS30GXX | Green | InGaN | 37 | 3.2 | Common Anode | Black | INND-SS30GAB |
| | | | | | Common Cathode | Black | INND-SS30GCB |
| | | | | | Common Anode | Grey | INND-SS30GAG |
| | | | | | Common Cathode | Grey | INND-SS30GCG |
| INND-SS30BXX | Blue | InGaN | 7 | 3.2 | Common Anode | Black | INND-SS30BAB |
| | | | | | Common Cathode | Black | INND-SS30BCB |
| | | | | | Common Anode | Grey | INND-SS30BAG |
| | | | | | Common Cathode | Grey | INND-SS30BCG |
| INND-SS30WXX | White | InGaN | 19.3 | 3.2 | Common Anode | Black | INND-SS30WAB |
| | | | | | Common Cathode | Black | INND-SS30WCB |
| | | | | | Common Anode | Grey | INND-SS30WAG |
| | | | | | Common Cathode | Grey | INND-SS30WCG |

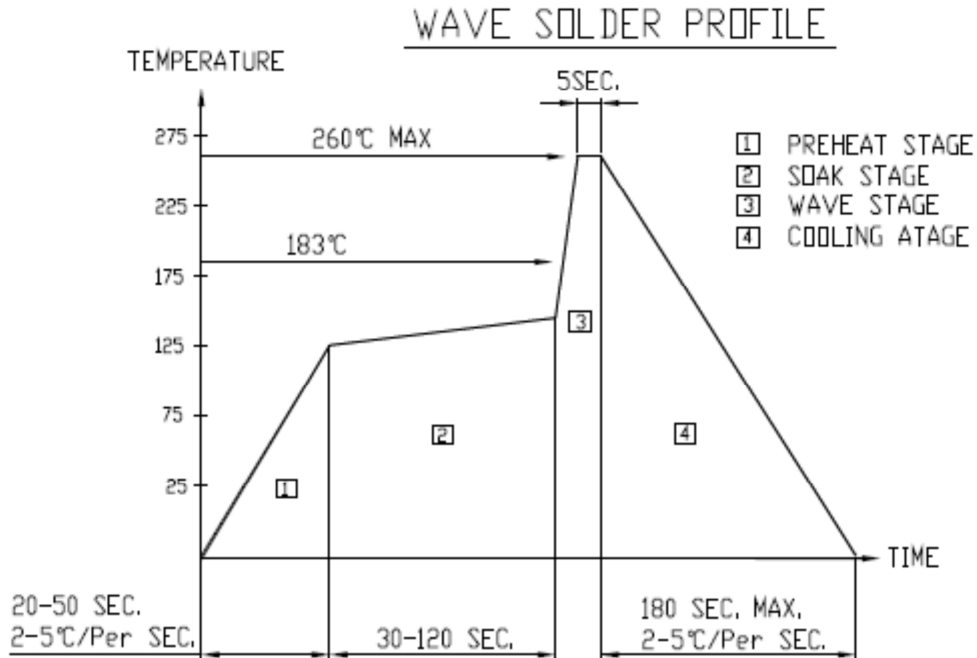
Label Specifications

Inolux P/N:

| I | N | N | D | - | S | S | 3 | 0 | X | X | X | - | X | X | X | X |
|--------|----------------------------|--------------------------|---|------------------------------|---|---|---|--|---|-----------------------|---|----------------------|---|---|---|---|
| Inolux | Display Type | Display Type | | Dimension | | Color | | Polarity | | Face Color | | Customized Stamp-off | | | | |
| | ND = Numeric Display | S: SMD Type S: Single | | 30 = 0.30" Display Height | | YG: 570 nm Y: 590 nm A: 605 nm R: 630 nm DR: 660 nm G: 525 nm B: 465 nm W: X: 0.27 Y: 0.25 | | A = Common Anode C=Common Cathode | | B = Black G = Grey | | | | | | |

Lot No.:

| | | | | | | | |
|------------------|--------------------------|---|---|---|-------|------|--------|
| Z | 2 | 0 | 1 | 7 | 01 | 24 | 001 |
| Internal Tracker | Year (2017, 2018,) | | | | Month | Date | Serial |

Reflow Soldering



Soldering Iron

Basic Spec is ≤ 4 sec. when 260°C (+10°C \rightarrow -1 second). Power dissipation of Iron should be less than 15W. Surface temperature should be under 230°C

Rework

Rework should be completed within 4 second under 245°C

Revision History

| Changes since last revision | Page | Version No. | Revision Date |
|-----------------------------|------|-------------|---------------|
| Initial Release | | 1.0 | 07-12-2017 |
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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.